

Features

- Two Independent Drivers, Each Capable of Sourcing and Sinking 5A
- CMOS and TTL Compatible Inputs
- Independent Enable for Each Driver
- 5V to 20V Supply Voltage Range
- -40°C to +125°C Extended Operating Temperature Range
- ±4kV ESD Rating (Human Body Model)
- Thermally enhanced 8-lead SOIC package
- Under Voltage Lockout Circuitry
- Fast Propagation Delays (16ns typical)
- Fast Rise and Fall Times (7ns typical)

Applications

- Switch-Mode Power Supplies
- DC-DC Converters
- Motor Controllers
- Power Inverters







Description

The IX4340 is a dual, high current, low side gate driver. Each of the two outputs is capable of sourcing and sinking 5A of peak current, and has a maximum voltage rating of 20V. The two outputs can be paralleled for higher current applications. Fast propagation delay times (16ns typical) and fast rise and fall times (7ns) make the IX4340 well suited for high frequency applications.

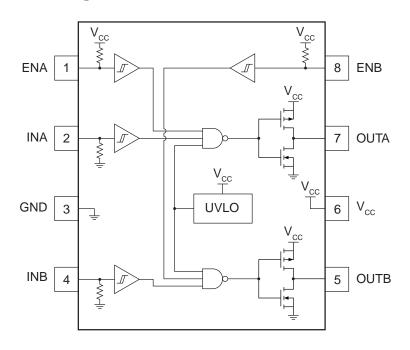
The inputs are TTL and CMOS logic compatible, and there is an independent Enable function for each output. Under voltage lockout circuitry (UVLO) prevents the high side source driver from conducting until there is sufficient supply voltage. The outputs are held low if the logic inputs are floating.

The IX4340 is available in a thermally enhanced 8-pin SOIC package.

Ordering Information

Part Number	Description
	8-Pin SOIC w/ Exposed Thermal Pad (100/Tube)
	8-Pin SOIC w/ Exposed Thermal Pad (4000/Reel)

IX4340 Functional Block Diagram





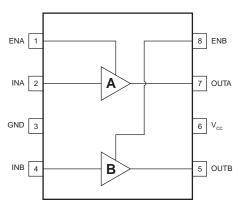
Specifications	3
1.1 Pin Configuration	3
1.2 Logic Table	3
1.1 Pin Configuration 1.2 Logic Table 1.3 Pin Definitions 1.4 Absolute Maximum Ratings	3
1.4 Absolute Maximum Ratings	3
1.5 Electrical Characteristics	4
1.6 Thermal Characteristics.	4
Performance Data	5
B. Manufacturing Information	7
B. Manufacturing Information	7
3.2 ESD Sensitivity	7
3.3 Soldering Profile.	7
3.2 ESD Sensitivity 3.3 Soldering Profile. 3.4 Board Wash	7
3.5 Mechanical Dimensions	۶

2



Specifications

1.1 Pin Configuration



1.2 Logic Table

IXx	ENx	V _{CC}	OUTx
1	1	V _{CC} >UVLO _{ON}	1
0	1	V _{CC} >UVLO _{ON}	0
Х	0	V _{CC} >UVLO _{ON}	0
Х	х	V _{CC} <uvlo<sub>ON</uvlo<sub>	0

1.3 Pin Definitions

Pin#	Name	Description		
1	ENA	Enable input for Channel A. A logic high (or floating) enables Channel A (the state of OUTA is determined by INA). A logic low disables OUTA (OUTA held low regardless of INA).		
2	INA	Channel A logic input. Internally pulled to GND.		
3	GND	Ground. Common ground reference for the device.		
4	INB	Channel B logic input. Internally pulled to GND.		
5	OUTB	Channel B output, capable of sourcing and sinking 5A		
6	V_{CC}	Supply Voltage.		
7	OUTA	Channel A output, capable of sourcing and sinking 5A		
8	ENB	Enable input for Channel B. A logic high (or floating) enables Channel B (the state of OUTB is determined by INB). A logic low disables OUTB (OUTB held low regardless of INB).		
The the	The thermal pad on the bottom of the device may be connected to GND or left floating; it must not be connected to any other net.			

The thermal pad is not intended to carry current.

1.4 Absolute Maximum Ratings

Parameter	Symbol	Minimum	Maximum	Units
Supply Voltage	V _{CC}	-0.3	20	V
Input Voltage	V _{IN}	-0.3	20	V
Output Current	I _{OUT}	-	±5	Α
ESD Rating (Human Body Model)	V _{ESD}	-4000	+4000	V
Junction Temperature	T _J	-55	+150	°C
Storage Temperature	T _{STG}	-65	+150	°C

Absolute maximum electrical ratings are at T_A=25°C

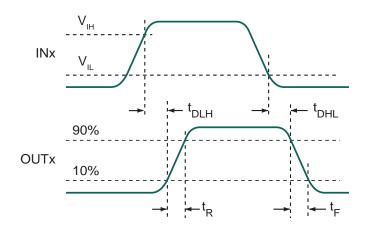
Absolute maximum ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.



1.5 Electrical Characteristics

 V_{CC} = 12V, T_J = -40°C to +125°C, unless otherwise noted.

Parameter	Conditions	Symbol	Minimum	Typical	Maximum	Units
Supply						
Supply Current	OUTA and OUTB Open	Icc	-	1.4	2.5	mA
Under Voltage Lockout (UVL	O)		1	l	Ш	
UVLO Rising Threshold	V _{CC} Rising	UVLO _{ON}	3.5	3.85	4.2	
UVLO Falling Threshold	V _{CC} Falling	UVLO _{OFF}	3.1	3.3	3.5	٧
UVLO Threshold Hysteresis	-	UVLO _{HYS}	0.2	0.5	0.8	
Logic Inputs (INA, INB, ENA	, ENB)		1	l	Ш	
Input Low Voltage	•	V _{IL}	-	-	8.0	V
Input High Voltage	-	V _{IH}	2.5	-	-	V
Output Drivers (OUTA, OUT	3)	1	1	I	Ш	
Output Pull-Up Resistance	I _{OUT} = -100mA, T _J = 25°C	R _{OH}	-	1	1.5	
	I _{OUT} = -100mA	HOL	-	1.3	1.8	0
Output Pull-Down Resistance	I _{OUT} = 100mA, T _J = 25°C	D.	-	0.6	1.1	Ω
	I _{OUT} = 100mA	R _{OL}	-	0.8	1.4	
Rise Time	C _{LOAD} = 1.8nF	t _R	-	7	15	
Fall Time	C _{LOAD} = 1.8nF	t _F	-	7	15	
Propagation Delay, Low to High	C _{LOAD} = 1.8nF	t _{DLH}	5	16	30	ns
Propagation Delay, High to Low	C _{LOAD} = 1.8nF	t _{DHL}	5	16	30	
Propagation Delay Matching	-	t _M	-5	-	5	



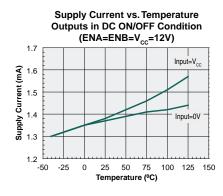
1.6 Thermal Characteristics

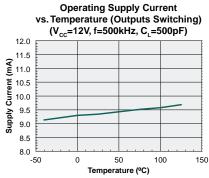
Parameter	Symbol	Rating	Units
Thermal Impedance, Junction-to-Ambient	$\theta_{\sf JA}$	85	°C/W
Thermal Impedance, Junction-to-Case	$\theta_{\sf JC}$	10	°C/W

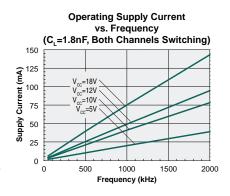


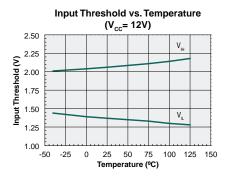
2 Performance Data

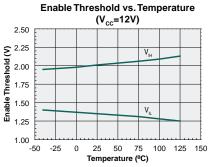
Unless otherwise noted, data presented in these graphs is typical of device operation at T_A=25°C.

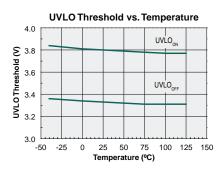


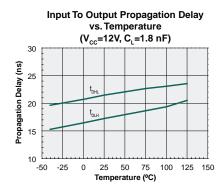


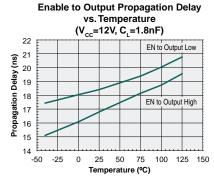


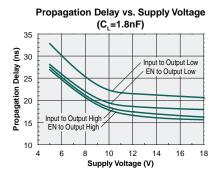




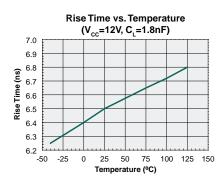


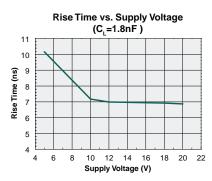


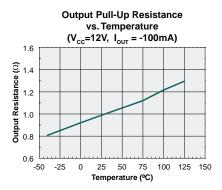


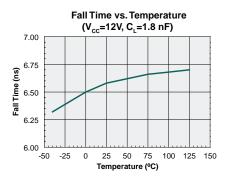


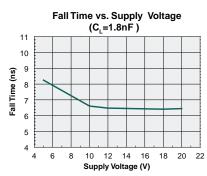


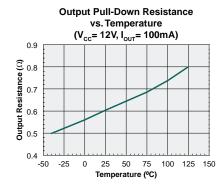














3 Manufacturing Information

3.1 Moisture Sensitivity

All plastic encapsulated semiconductor packages are susceptible to moisture ingression. IXYS Integrated Circuits Division classifies its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** classification as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Classification
IX4340NE	MSL 1

3.2 ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

3.3 Soldering Profile

Provided in the table below is the Classification Temperature (T_C) of this product and the maximum dwell time the body temperature of this device may be (T_C - 5)°C or greater. The classification temperature sets the Maximum Body Temperature allowed for this device during lead-free reflow processes. For through-hole devices, and any other processes, the guidelines of J-STD-020 must be observed.

Device	Classification Temperature (T _C)	Dwell Time (t _p)	Max Reflow Cycles
IX4340NE	260°C	30 seconds	3

3.4 Board Wash

IXYS Integrated Circuits Division recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to flux or solvents that are Chlorine- or Fluorine-based.





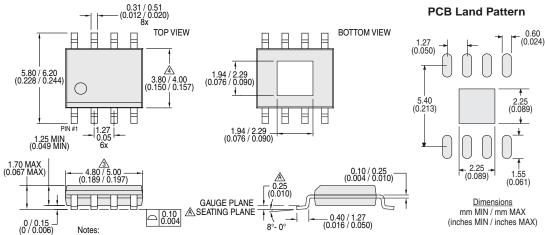




3.5 Mechanical Dimensions

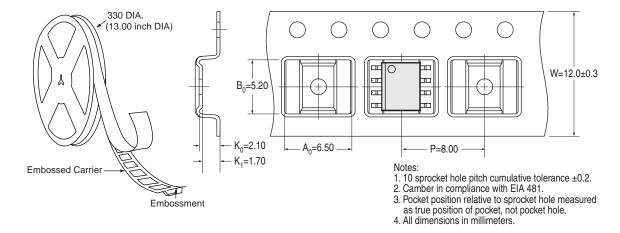
3.5.1 IX4340NE Package Dimensions

The thermal pad on the bottom of the device may be connected to GND or left floating; it must not be connected to any other net. The thermal pad is not intended to carry current.



- 1. All dimensions are in mm (inches).
- 2. This package conforms to JEDEC Standard MS-012, variation BA, Rev. F.
- ⚠ Dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15mm per end.
 ⚠ Dimension does not include interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.25mm per side.

3.5.2 Tape & Reel Dimensions



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